

TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

# SSM3K37MFV

High Speed Switching Applications

Analog Switch Applications

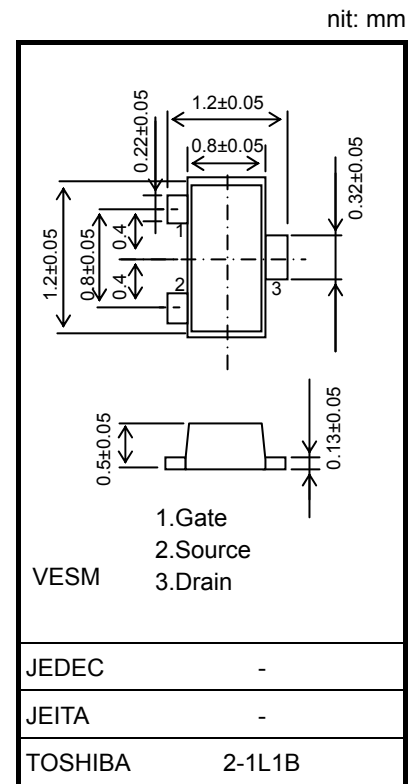
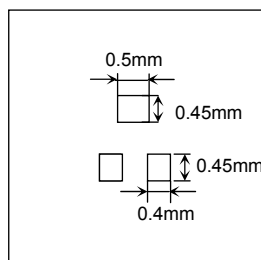
- 1.5-V drive
- Low ON-resistance
  - $R_{DS(ON)} = 5.60\Omega$  (max) (@ $V_{GS} = 1.5$  V)
  - $R_{DS(ON)} = 4.05\Omega$  (max) (@ $V_{GS} = 1.8$  V)
  - $R_{DS(ON)} = 3.02\Omega$  (max) (@ $V_{GS} = 2.5$  V)
  - $R_{DS(ON)} = 2.20\Omega$  (max) (@ $V_{GS} = 4.5$  V)

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	20	V
Gate-source voltage		$V_{GSS}$	±10	V
Drain current	DC	$I_D$	250	mA
	Pulse	$I_{DP}$	500	
Drain power dissipation (Ta = 25°C)		$P_D$ (Note 1)	150	mW
Channel temperature		$T_{ch}$	150	°C
Storage temperature		$T_{stg}$	-55 to 150	°C

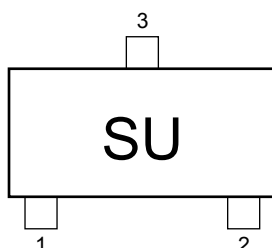
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a FR4 board (25.4 mm × 25.4 mm × 1.6 mm)

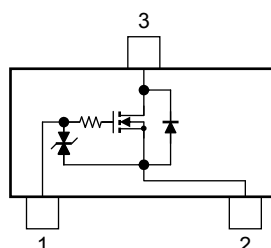


Weight: 1.5mg (typ.)

## Marking



## Equivalent Circuit



Start of commercial production  
2010-02

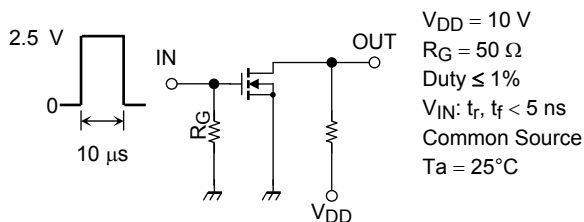
## Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	20	—	—	V
	$V_{(BR)DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	—	—	
Drain cutoff current	$I_{DSS}$	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	$\mu\text{A}$
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	—	1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 100 \text{ mA}$ (Note 2)	0.14	0.28	—	S
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = 100 \text{ mA}, V_{GS} = 4.5 \text{ V}$ (Note 2)	—	1.65	2.20	$\Omega$
		$I_D = 50 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note 2)	—	2.16	3.02	
		$I_D = 20 \text{ mA}, V_{GS} = 1.8 \text{ V}$ (Note 2)	—	2.66	4.05	
		$I_D = 10 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note 2)	—	3.07	5.60	
Input capacitance	$C_{iss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	12	—	pF
Output capacitance	$C_{oss}$		—	5.5	—	
Reverse transfer capacitance	$C_{rss}$		—	4.1	—	
Switching time	Turn-on time	$t_{on}$	$V_{DD} = 10 \text{ V}, I_D = 100 \text{ mA}$		—	ns
	Turn-off time	$t_{off}$	$V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 50 \Omega$		—	
Drain-source forward voltage	$V_{DSF}$	$I_D = -250 \text{ mA}, V_{GS} = 0 \text{ V}$ (Note 2)	—	-0.9	-1.2	V

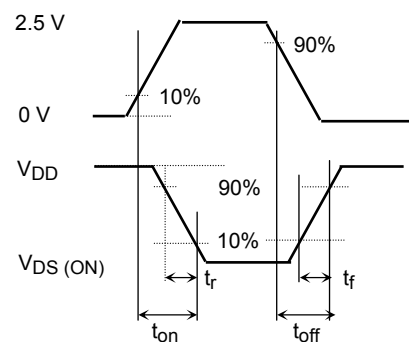
Note2: Pulse test

## Switching Time Test Circuit

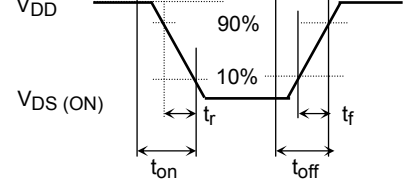
### (a) Test Circuit



### (b) $V_{IN}$



### (c) $V_{OUT}$



## Precaution

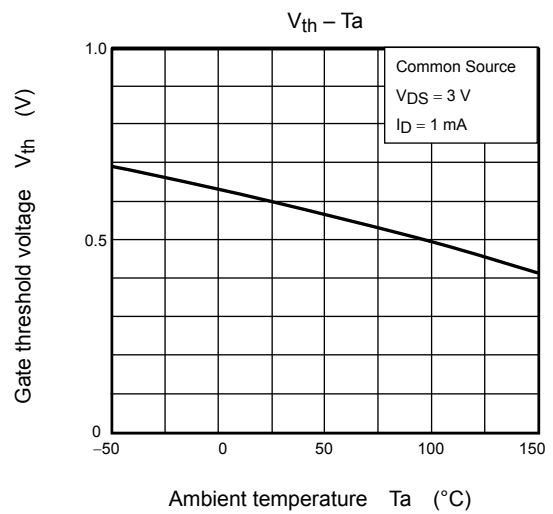
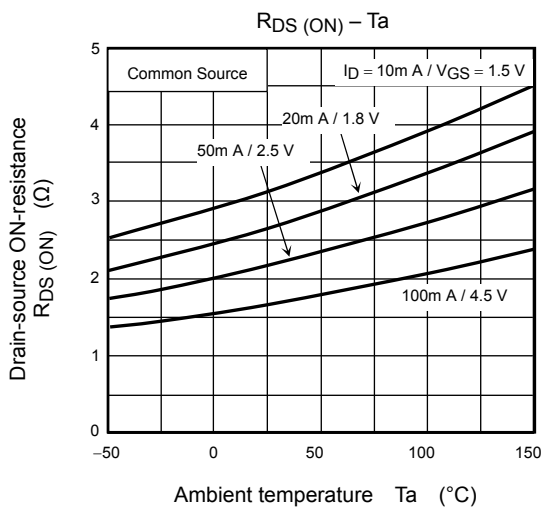
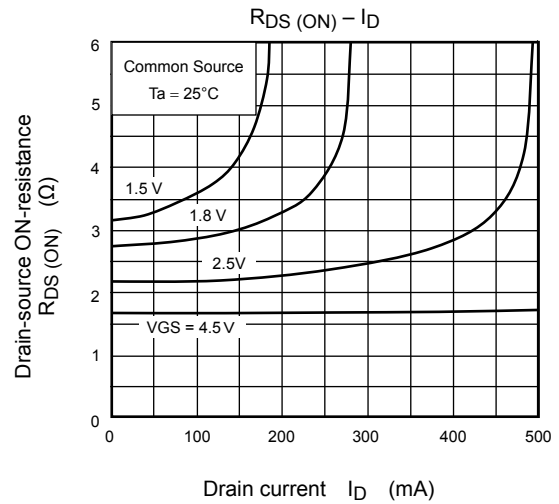
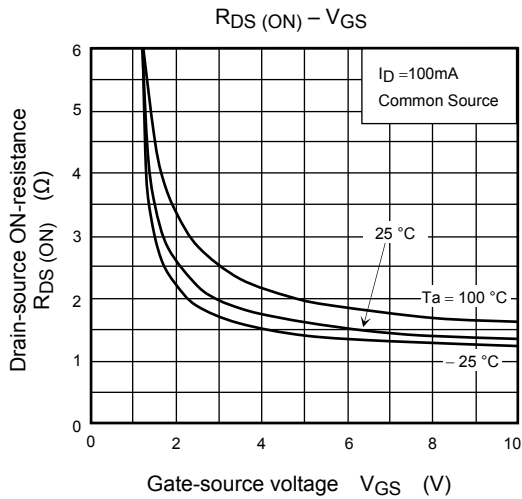
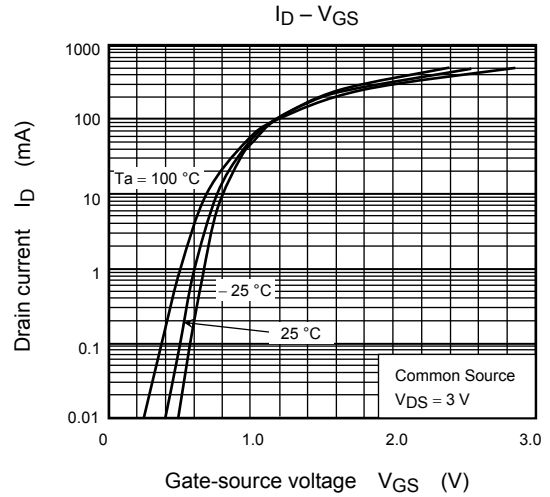
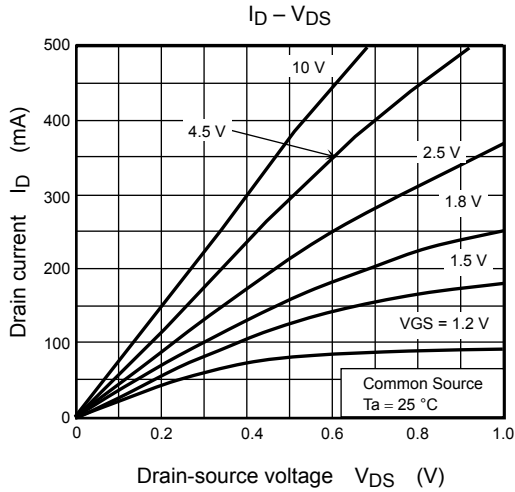
$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = 1 \text{ mA}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .)

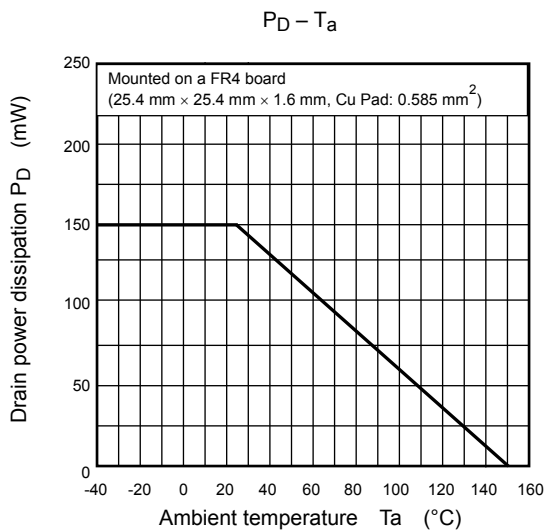
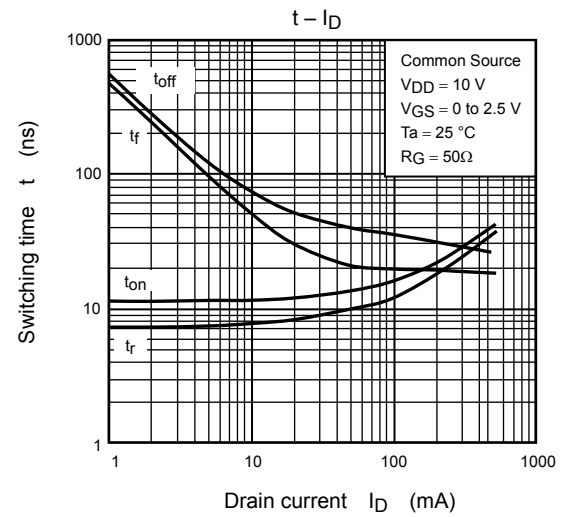
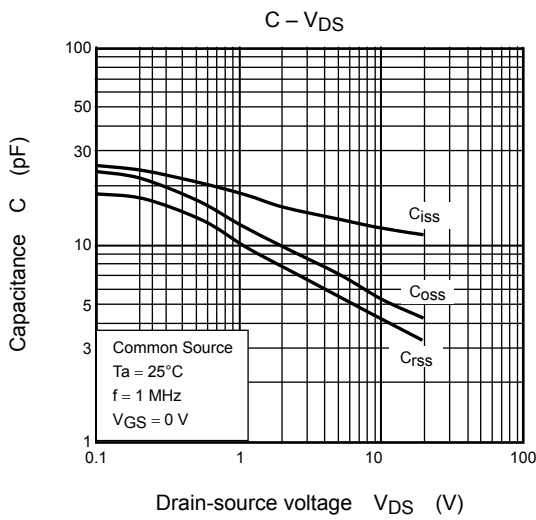
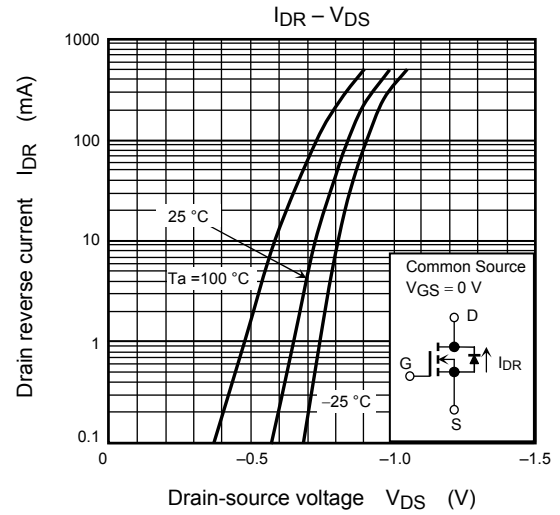
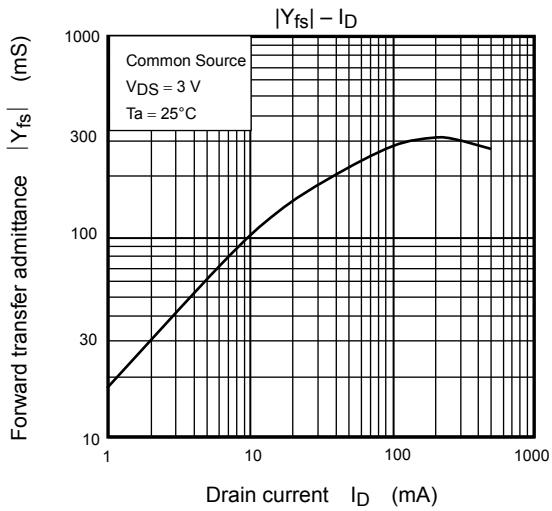
Take this into consideration when using the device.

Do not use this device under avalanche mode. It may cause the device to break down.

## Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.





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